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Dynamical Mean-Field Theory description of the voltage induced transition in a non-equilibrium superconductor

A. Amaricci[1] and M. Capone[1]

[1] *Democritos National Simulation Center, Consiglio Nazionale delle Ricerche, Istituto Officina dei Materiali and Scuola Internazionale Superiore di Studi Avanzati, Via Bonomea 265, 34136 Trieste, Italy*

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Using dynamical mean-field theory (DMFT) we study a simplified model for heterostructures involving superconductors. The system is driven out-of-equilibrium by a voltage bias, imposed as an imbalance of chemical potential at the interface. We solve the self-consistent DMFT equations using iterative second-order perturbation theory in the Nambu-Keldysh formalism. We show that the superconducting state is destabilized by voltage biases of the order of the energy gap. We demonstrate that the transition to the normal state occurs through an intermediate *bad superconducting* state, which is characterized by a smaller value of the order parameter and incoherent excitations. We discuss the energetic balance behind the stabilization of such exotic superconducting state.

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I. INTRODUCTION.

The unstoppable advances in the engineering of heterostructures based on transition-metal oxides is setting the pace for their theoretical investigation. A variety of phenomena has been reported through the combination of different geometries and the rich physics of the constituents, which range from colossal magnetoresistance manganites to high-temperature superconducting cuprates[1–4]. There is no need to stress the importance, also for applications in electronics, of superconducting heterostructures and of the possibility to control their conduction properties via a gate voltage[5–7]. However, even if our ability to theoretically describe strongly correlated electron systems in confined geometries is reaching remarkable levels[8], a full understanding of the non-equilibrium properties of driven superconducting heterostructures remains a formidable task, which requires to take some intermediate steps before a full microscopic modelling can be achieved.

In this work we perform one step in this direction, considering the ballistic transport in an idealized superconductor subject to an external bias. Extending to the superconducting state a proposal introduced in Ref. 9, we consider a simplified model for the bulk properties of a system subject to a finite voltage bias. The potential drop occurs essentially at the interfaces of the superconductor with the normal source/drain leads[7,10,11], which in turn are located sufficiently far in space, while the potential profile is essentially constant in the bulk. The underlying idea is that the charge imbalance taking place at the interfaces injects into the system evanescent electronic states[12,13] at the bias energy, which rapidly reach a ballistic regime. Thus in the stationary limit and for the bulk, the presence of a voltage bias is accounted for through the existence of electrons propagating in the same or in the opposite direction with respect to the driving field, respectively *Left* or *Right* movers, with unbalanced energies set by the voltage bias at the two leads.

Although this simplified construction can not capture the full non-equilibrium physics of a driven bulk superconductor, it allows us to get insight into the effect of dephasing, which is expected to be particularly relevant in heterostructures as long as the motion of the carriers can be described as ballistic. As for the interaction leading to superconductivity we consider the simplest case of an instantaneous local interaction, as described by an attractive Hubbard model.

While the effect of a voltage bias on a Bardeen-Cooper-Schrieffer (BCS) superconductor is well established[14,15], much less is known about intermediate and strong-coupling superconductors. These regimes require to go beyond the BCS approximation and the use of nonperturbative approaches like Dynamical Mean-Field Theory (DMFT)[16]. This method allows to follow the evolution of statical and dynamical properties of the superconducting state as a function of physical parameters[17–20] and external stimuli. The DMFT has been successfully applied to heterostructures formed by normal metallic leads separated by a strongly correlated barrier material in order to study transport and spectral properties at equilibrium[21–25] and in a steady state[26]. The effect of a voltage bias in a correlated metal has been investigated in[9], pointing out the existence of a critical voltage for the metal-insulator transition. Recently a non-equilibrium extension of the DFMT[27,28] has been used to study the dynamics of driven strongly correlated systems[29–31], including inhomogeneous normal setup[32].

Our calculations show that an intermediate-coupling superconducting state is essentially untouched by biases smaller than the energy gap. Interestingly, as the voltage is increased, the phase transition to a normal (non superconducting) state is preceded by the formation of an intermediate *bad*-superconducting state for biases immediately larger than the energy gap. In this region, the bias leads to an incoherent motion of the carriers which results in a superconductor with a smaller energy gap and a finite scattering rate, while the superfluid stiffness is slightly enhanced with respect to equilibrium. Eventu-

ally the system turns into an insulating state of incoherent preformed pairs for very large bias. We characterize the two transitions via the evolution of the spectral properties and of the characteristic energy scales contributing to the stabilization of the bad superconductor and draw a phase diagram in the interaction-voltage plane.

In the following Sec. II we discuss the approximation scheme, we derive the main model and discuss its method of solution with the Nambu-Keldysh stationary DMFT. In Sec. III we present our main results, namely the progressive loss of coherence of the quasiparticles leading to the breakdown of the superconducting state. We discuss the formation of an intermediate bad-superconducting state and the phase-diagram of the model for the intermediate-to-strong regime of attraction. In Sec. IV we characterize the formation of the bad-superconducting state by means of its energy balance. Finally in Sec. V we present our conclusions and discuss some future perspectives of this work.

II. METHOD.

We consider a three-dimensional superconductor in presence of an electric field closely following an approach proposed in Ref. 9 for a correlated metallic system. We work in the Coulomb gauge, where the constant field corresponds to static potential difference between the external normal source/drain leads. As we are interested in the bulk properties of the system, we shall assume that the external leads are located far in space from the bulk region of interest. The charge recombination takes place at the interface of the superconductor with the normal leads.

In the stationary limit the properties of such system are determined by the non-equilibrium electronic distribution $f(\omega)$, which in turn can be separated a particle-hole symmetric component and an asymmetric component describing the charge imbalance in the device. The spirit of this work is to focus on the bulk properties by neglecting the effects of the charge-imbalance part.

This simplification is justified by the fact that in the superconducting regime the electrostatic potential at the center of the device is essentially constant[10], while most of the potential drop occurs in proximity of the interface to the normal leads. This makes the charge imbalance negligible in the bulk. Note that this situation is different from the normal case, for which the potential profile is almost linear in the insulating regime and flat in the metallic regime[25].

Thus, in the stationary limit the effect of the voltage bias onto the superconducting bulk can be described in terms of the existence of carriers at energies $\pm\Phi/2$ of the leads, moving ballistically along the direction set by the potential difference. Thus, independently of the actual dimensions of the system, we classify the lattice electrons in two sets, namely of left- (L) and right- (R) moving carriers with a local energy potential $V_L = +\Phi/2$ and $V_R = -\Phi/2$. This decomposition reflects the presence at the bulk of a preferred direction corresponding to an electric field associated to the bias. The physical destruction (creation) operators of an orbital electron at site i with spin σ can thus be decomposed in the superposition of L and R electrons, *i.e.* $c_{i\sigma} = \frac{1}{\sqrt{2}}(c_{i\sigma L} + c_{i\sigma R})$. We further assume an attractive interaction, which we model as on-site attractive Hubbard U. The interaction obviously acts on the physical electrons and gives rise to pairing and superconductivity. Our starting point is the Hamiltonian:

$$\mathcal{H} = -t \sum_{\langle ij\rangle\sigma} \sum_{\alpha=L,R} \left(c^{+}_{i\sigma\alpha} c_{j\sigma\alpha} + h.c.\right) - |U| \sum_{i} n_{i\uparrow} n_{i\downarrow} \quad (1)$$

where the first (kinetic) terms describes the ballistic motion of the two species of movers, and the interaction is associated to the densities of physical electrons $n_{i\sigma} = c^{\dagger}_{i\sigma} c_{i\sigma}$. The model can be simplified by an orthogonal transformation to *even* (E) and *odd* (O) states $c_{i\sigma E/O} = \frac{1}{\sqrt{2}}(c_{i\sigma L} \pm c_{i\sigma R})$, where the E combination coincides with the physical electron. In this basis, the interaction term obviously contains only E electrons and the motion of the O component is decoupled and trivial, as it is controlled only by the hopping term. We consider the half-filling condition of one particle per site corresponding to set the chemical potential to $\mu = |U|/2$.

Thanks to the bulk approximation scheme introduced above we can solve the model (1) by means of the DMFT in the Keldysh formalism. Within DMFT, the lattice problem is reduced to an effective single impurity model[16,20]. DMFT allows to study directly the superconducting state of the system introducing anomalous Green's function and self-energy associated to the evolution of Cooper pairs. Then we can use a Nambu spinor formalism, in which diagonal elements of the 2×2 self-energy matrix are normal components and off-diagonal ones are the superconducting components[19,20]. Starting the self-consistency equation with a finite anomalous Green's function, the self-consistent loop will find superconducting solutions if they are allowed by the physics, and it will correctly describe the disappearance of superconductivity as a function of control parameters.

We use iterative perturbation theory method (IPT), extended to deal with superconductivity[17], to solve the effective impurity problem. This method provides a simple but reasonably accurate solver, which is straightforwardly extended to the Keldysh formalism in real-time and real-frequency and, importantly, gives direct access to the local spectral functions. In the IPT method the self-energy function $\hat{\Sigma}$ is expressed as: $\hat{\Sigma} = \hat{\Sigma}_{\rm HFB} + U^2 \hat{\Sigma}^{(2)}$, where $\Sigma^{r}_{\rm HFB} = -\frac{|U|}{2} n \tau_3 - \Delta \tau_1$ is the the Hartree-Fock-Bogoliubov (HFB) term, $\Delta = -|U| \langle c_{o\uparrow} c_{o\downarrow} \rangle$ is the superfluid amplitude of the impurity and $\tau_{i=1,2,3}$ are the Pauli matrices. $\hat{\Sigma}^{(2)}$ is the 2^{nd}-order contribution to the self-energy, which in terms of the Keldysh components of the

HFB-corrected Weiss-Field: $\hat{\tilde{\mathcal{G}}} = (\hat{\mathcal{G}}_0^{-1} - \hat{\Sigma}_{\rm HFB})^{-1}$ reads:

$$\begin{aligned}\Sigma_{11}^{(2)\lessgtr}(t) &= \left[\tilde{\mathcal{G}}_{11}^{\lessgtr}(t)\tilde{\mathcal{G}}_{22}^{\lessgtr}(t) - \tilde{\mathcal{F}}_{12}^{\lessgtr}(t)\tilde{\mathcal{F}}_{21}^{\lessgtr}(t)\right]\tilde{\mathcal{G}}_{22}^{\gtrless}(-t) \\ S_{12}^{(2)\lessgtr}(t) &= \left[\tilde{\mathcal{F}}_{12}^{\lessgtr}(t)\tilde{\mathcal{F}}_{21}^{\lessgtr}(t) - \tilde{\mathcal{G}}_{11}^{\lessgtr}(t)\tilde{\mathcal{G}}_{22}^{\lessgtr}(t)\right]\tilde{\mathcal{F}}_{12}^{\gtrless}(-t)\end{aligned} \quad (2)$$

while the retarded components are obtained from the general relation $F^r(t) = \theta(t)(F^>(t) - F^<(t))$.

The self-consistency condition is fulfilled by imposing to the retarded component of the Weiss field to obey the relation: $\hat{\mathcal{G}}_0^{r\,-1}(\omega) = \hat{G}^{r\,-1}(\omega) + \hat{\Sigma}^r(\omega)$, where $\hat{G}^r(\omega) = \int d\varepsilon D(\varepsilon)\hat{G}^r(\varepsilon,\omega)$ is the real-frequency local retarded Green's function and $D(\varepsilon)$ is the non-interacting density of state of the lattice. Here we use a semicircular density of states $D(\varepsilon) = 2\sqrt{D^2-\varepsilon^2}/\pi D^2$ of half-bandwidth D (that we set as our energy unit), which has been shown to describe accurately three-dimensional systems, and substantially simplifies the self-consistency equations, thereby reducing numerical errors which can be particularly dangerous out of equilibrium. Because of its local nature, the DMFT calculations depend very weakly on the lattice structure. Thus, our results are qualitatively valid for any other choice of the underlying lattice structure.

Finally, the other Keldysh components of the Weiss field are obtained through the spectral representation as:

$$\begin{bmatrix}\tilde{\mathcal{G}}_{11}^{\lessgtr}(t) \\ \tilde{\mathcal{F}}_{12}^{\lessgtr}(t)\end{bmatrix} = \mp\frac{i}{2\pi}\int d\omega \begin{bmatrix}{\rm Im}\tilde{\mathcal{G}}^r(\omega) \\ {\rm Im}\tilde{\mathcal{F}}^r(\omega)\end{bmatrix} f(\pm\omega)e^{-i\omega t} \quad (3)$$

where $f(x) = \sum_{\alpha=\pm} f_{FD}(x + \alpha\Phi/2)$ is the effective-bath distribution function, given by the symmetric combination of the Left/Right moving electrons distribution, as follow from the initial assumptions, and f_{FD} is the Fermi-Dirac function. This equation expresses, within our local approximation of the lattice problem, the effects of the continuous energy mismatch brought in by the presence of the voltage bias. A similar expression can be derived for the order parameter within the BCS theory[14,15], to describe the progressive destruction of the superconducting order as effect of a voltage bias. Our Eq. (3) reduces to an approximated version of such BCS equation for the order parameter in the limit of very weak attraction, in agreement with the nature of the bulk approximation.

Finally, we determine the remaining Keldysh components of the normal and anomalous Green's function using the following relations:

$$\begin{aligned}G_{22}^{\lessgtr}(\omega) &= -G_{11}^{\gtrless}(-\omega) \\ F_{21}^{\lessgtr}(\omega) &= -F_{12}^{\lessgtr\,*}(\omega) \\ G_{22}^{r}(\omega) &= G_{11}^{r\,*}(-\omega) \\ F_{21}^{r}(\omega) &= F_{12}^{r\,*}(-\omega)\end{aligned} \quad (4)$$

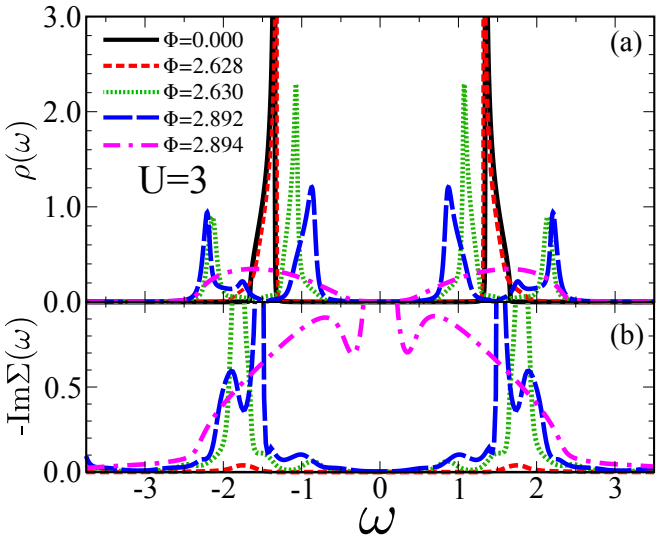

Figure 1. (Color online) Evolution of the spectral function $\rho(\omega) = -{\rm Im}G_{11}^r(\omega)/\pi$ (a) and of the imaginary part of the normal self-energy $-{\rm Im}\Sigma_{11}^r(\omega)$ (b) as a function of the voltage bias Φ for $U = 3$.

III. RESULTS.

In the absence of any bias ($\Phi = 0$) the attractive Hubbard model describes a superconducting (SC) to normal phase-transition at a critical temperature $T_c(U)$[19,20] for any value of the carrier density and the interaction. While the modulus of the order parameter $P = 1/N\sum_i\langle c_{i\uparrow}c_{i\downarrow}\rangle$ and the energy gap E_g^0 monotonically increase as a function of U, the critical temperature displays a maximum at an intermediate value of U of the order of the bandwidth, roughly separating the BCS-like behavior at weaker coupling from the strong-coupling or Bose-Einstein-Condensate (BEC) regime. In this latter case the large pairing strength locks the fermions in strongly bounded local pairs, which delocalize with a suppressed hopping amplitude proportional to t^2/U.

In this work we focus on the intermediate-to-strong coupling regime, where the BCS approach does not apply. Because of the assumptions behind the bulk approximation scheme, we expect our method to better describe the intermediate-to-strong attracting regime, where the coherence length scale is shorter.

We investigate how the presence of an external bias destabilizes the SC state for different values of U in the half-filled case where the number of electrons is identical to the number of sites[33].

In Fig.1 we show the evolution of the single-particle spectral density $\rho(\omega) = -{\rm Im}G_{11}^r(\omega)/\pi$ and of the single-particle self-energy ${\rm Im}\Sigma_{11}^r(\omega)$ by increasing the bias at $U = 3$. At zero bias $\Phi = 0$ the spectrum displays narrow coherence peaks at the equilibrium gap edges $\pm E_g^0/2$. Within IPT the incoherent part of the spectral weight is split into a narrow peak and a satellite at higher energy (not shown in the figure). This is a consequence of the

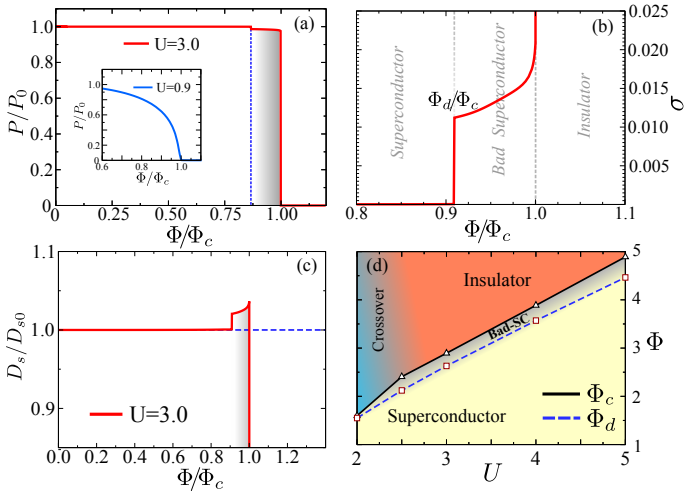

Figure 2. (Color online) (a) Order parameter P, normalized to its equilibrium value P_0, for $U=3$ ($P_0=1.414$) and $U=0.9$ (inset, $P_0=0.169$). (b) Scattering rate σ for $U=3$. (c) Normalized superfluid stiffness D_s/D_0 for $U=3$. (d) Φ-U phase-diagram of the model. Dashed line shows the transition to a bad superconducting regime. Solid line indicates the transition to the normal phase.

vanishing of the imaginary part of the normal self-energy for $|\omega| < \frac{3E_g^0}{2}$ as follows from the Eq. 2 for a gapped system[18].

The effect of the bias on our strong coupling SC is extremely small as long as the bias Φ is substantially smaller than the equilibrium gap $E_g^0 \simeq 2.894$ for our choice of parameters. In this regime the spectral function essentially coincides with the equilibrium solution. In the same process a finite imaginary part of the self-energy very slowly develops at low-energy near $\pm E_g^0/2$ (see Fig. 1(b)), associated to an increased scattering rate $\sigma = -\mathrm{Im}\Sigma(\omega = E_g^\Phi)$, *i.e.* to a reduced lifetime of the single particle excitations at the gap edge. This effect is however negligible as long as the bias is smaller than a critical value $\Phi_d = 2.630 < E_g^0$ at which the system undergoes a discontinuous transition where the gap edge sharply drops to a lower value (green dotted curve in Fig.1). At the same time also other observables (see panels (a)-(c) in Fig.2) have a discontinuous change: The order parameter P has a small drop, while the scattering rate σ jumps to a larger value as well as the superfluid stiffness D_s. In this regime, the weight of $\mathrm{Im}\Sigma_{11}^r(\omega)$ in the range $|\omega| \geq E_g^0/2$ becomes more pronounced. This corresponds to further broadening of the coherence peaks in the spectral functions, *i.e.* to a progressive shortening of quasi-particles life-time.

Further increasing the voltage bias we reach a (second) critical value $\Phi_c > \Phi_d$ for which the system is no longer able to sustain the SC state, and undergoes a superconductor-to-normal phase transition, characterized by a profound change in the spectral functions and the observables. For our intermediate- and strong values of the interaction U, the final normal state is indeed an insulator formed by incoherent localized pairs. For $\Phi > \Phi_c$ the spectral density is characterized by the onset of completely incoherent bands centered at $\omega = \pm U/2$[34,35], analogous to the Hubbard bands in the repulsive Hubbard model. The self-energy accordingly diverges for $\omega \to 0$, see Fig. 1(b). Here the superfluid order parameter P and the superfluid stiffness drop to zero, while the scattering rate diverges, signaling the incoherent nature of this insulator.

In the inset of Fig.2(a) we show DMFT results for the order parameter obtained for a smaller value of $U=0.9$, for which the BCS scheme can be qualitatively used. Indeed our approach qualitatively reproduces the correct continuous reduction of the order parameter, as predicted by the BCS theory[14], confirming that the results obtained at larger U in DMFT do not depend on the bulk approximation. This result is directly linked to the structure of the equation Eq. (3), which in the weak-attraction regime reduces to an approximated result within the BCS theory[14,15].

In panel (d) of Fig. 2 we report a phase diagram as a function of the attraction U and the bias. The same transitions we described are indeed present for any $U>2$. Two transitions lines $\Phi_d(U)$, $\Phi_c(U)$ define a standard superconducting region, a bad superconductor and a poorly conducting or insulating normal state. Indeed the existence of the bad superconducting intermediate state appears to be limited to parameters for which the normal state is not a normal metal, but an incoherent insulator of preformed pairs[35].

IV. ENERGY BALANCE.

We now characterize the bad superconducting state and the reason behind its stabilization. In Fig.3 we show the variations of the kinetic and potential energy with respect to equilibrium as a function of the bias, $\Delta E = E(\Phi) - E(0)$. Interestingly, our results show that the bad superconductor has a lower kinetic energy and a higher potential energy with respect to its equilibrium counterpart. The increased potential energy amounts to a reduction of the energy gain associated to Cooper pair formation, and it is consistent with the reduction of the SC order parameter and of the spectral gap that we discussed before. However, the system is able to gain kinetic energy in the same process, compensating the dephasing effect of the bias.

This latter fact is crucial for the existence of the bad superconductor and is intimately related to the intermediate- and strong-coupling nature of the superconductor. In this regime, in fact, the system can be described as a collection of bound pairs which manage to establish phase coherence despite their limited mobility. This is in sharp contrast with the BCS regime, where delocalized pairs move across the system.

The external bias can help the preformed pairs to

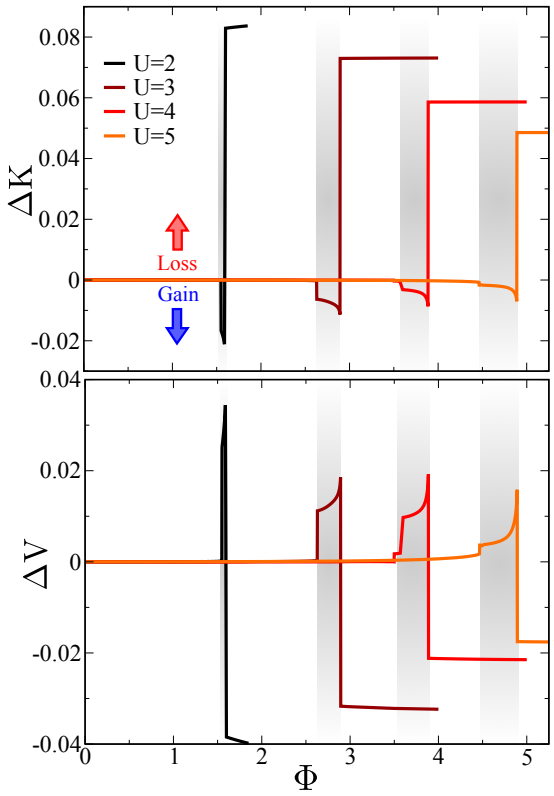

Figure 3. (Color online) Kinetic (left) and potential (right) energy variation, respectively ΔK and ΔV, as a function of the voltage bias Φ.

move, even if incoherently. This indeed leads to the gain in kinetic energy that we have reported in Fig.3 for the bad superconductor. The increased incoherent motion contrasts with the binding in pairs and leads to a loss in the potential energy. As a matter of fact the biased superconductor behaves as an equilibrium system with a smaller effective coupling, which indeed corresponds to a smaller potential energy gain, but also to a gain in kinetic energy. However, the bias also leads to processes giving rise to a finite scattering rate (see Fig.2(b)) which testify the incoherent nature of this intermediate superconducting state. It is precisely this reduced coherence which led us to define this state as a "bad superconductor".

Interestingly, the bad superconductor turns out to have a *larger* superfluid stiffness D_s than the equilibrium system, as reported in Fig.2(c). This result can be rationalized in terms of the two effects we described above. On one hand the bad superconductor is expected to have a reduction of superfluid stiffness as a consequence of the incoherence measured by the scattering rate. On the other hand, the energetic balance suggests that, to some extent, the bad superconductor can be regarded as an effectively weaker-coupling system. Indeed D_s naturally *increases* reducing the coupling[20]. The two effects are therefore competitive, but our DMFT calculations show that the effective reduction of the coupling prevails, leading to an overall increase of the superfluid density. We have verified that the observed increase is much smaller than the one associated to the effective reduction of the coupling.

Upon further increasing the voltage bias, the delicate balance which stabilizes the bad superconductor can no longer be sustained and the system undergoes a phase-transition in which all the residual kinetic energy in transformed into potential energy leading to formation of an insulator of preformed pairs.

V. CONCLUSIONS.

In this work we have investigated a model for non-equilibrium superconductivity. We solved the model using dynamical mean-field theory within iterative perturbation theory calculations. We find that the non-equilibrium stationary superconducting state is only destabilized by a voltage bias of the order of the gap. Our calculations show that the transition to the normal phase takes place in two steps: crossing a first critical line the system enters in a bad superconducting regime, characterized by more incoherent quasi-particles excitations and smaller superfluid amplitude. Eventually the bad superconductor turns into a insulator of completely incoherent preformed paris. The stabilization of this state is shown to intimately related to the intermediate/strong-coupling nature of pairing, in which tightly bound pairs are formed already in the normal state.

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